



SANYO Semiconductors

DATA SHEET

ECH8308 — P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Best suited for load switching.
- Low ON-resistance.
- 1.8V drive.
- Halogen free compliance.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-12	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		-10	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-40	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (900mm ² ×0.8mm)	1.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =-1mA, V _{GS} =0V	-12			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-12V, V _{GS} =0V			-10	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-6V, I _D =-1mA	-0.4		-1.3	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-6V, I _D =-5A	12	21		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-5A, V _{GS} =-4.5V		9.2	12.5	mΩ
	R _{DS(on)2}	I _D =-3A, V _{GS} =-2.5V		14	20	mΩ
	R _{DS(on)3}	I _D =-1A, V _{GS} =-1.8V		22	33	mΩ

Marking : JK

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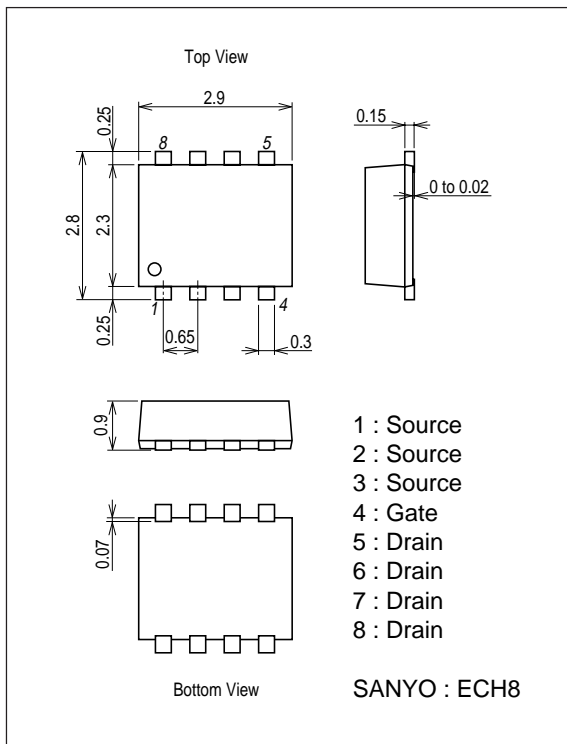
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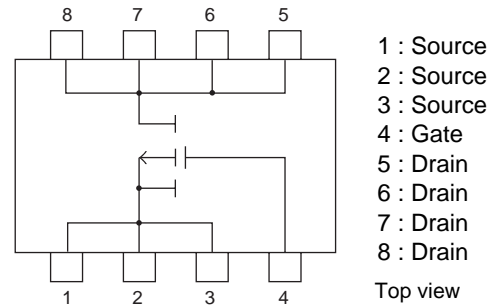
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS}=-6V, f=1MHz$		2300		pF
Output Capacitance	Coss	$V_{DS}=-6V, f=1MHz$		720		pF
Reverse Transfer Capacitance	Crss	$V_{DS}=-6V, f=1MHz$		550		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		24		ns
Rise Time	t_r	See specified Test Circuit.		130		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		230		ns
Fall Time	t_f	See specified Test Circuit.		195		ns
Total Gate Charge	Qg	$V_{DS}=-6V, V_{GS}=-4.5V, I_D=-10A$		26		nC
Gate-to-Source Charge	Qgs	$V_{DS}=-6V, V_{GS}=-4.5V, I_D=-10A$		4.0		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=-6V, V_{GS}=-4.5V, I_D=-10A$		7.1		nC
Diode Forward Voltage	V_{SD}	$I_S=-10A, V_{GS}=0V$		-0.79	-1.2	V

Package Dimensions

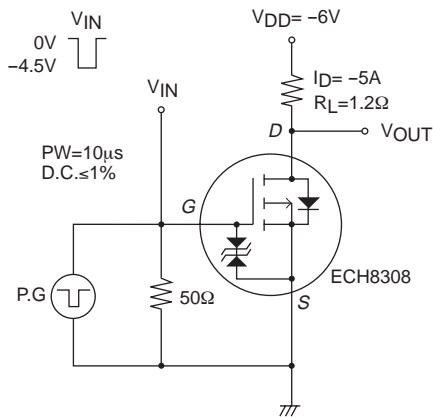
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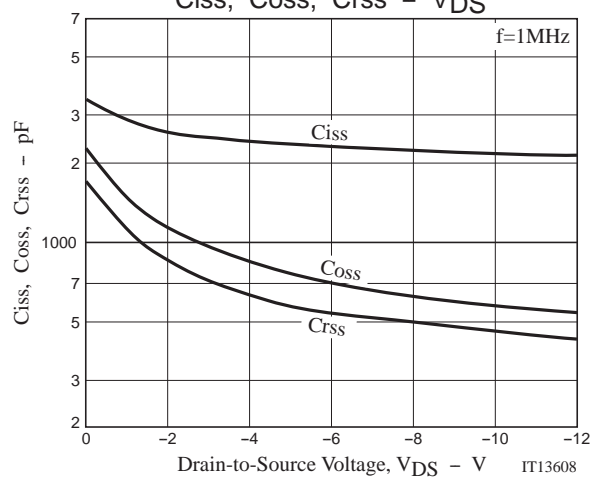
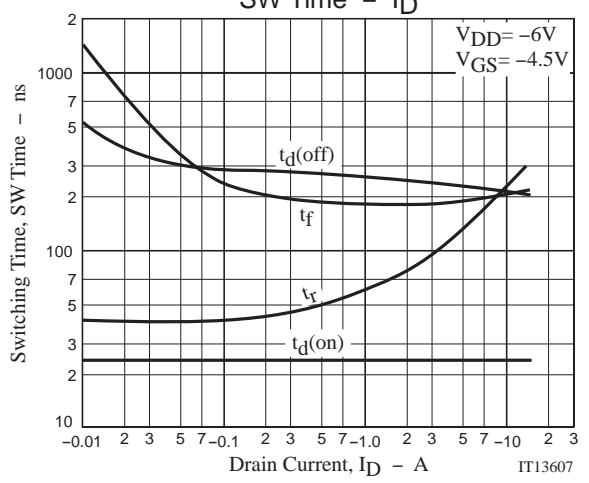
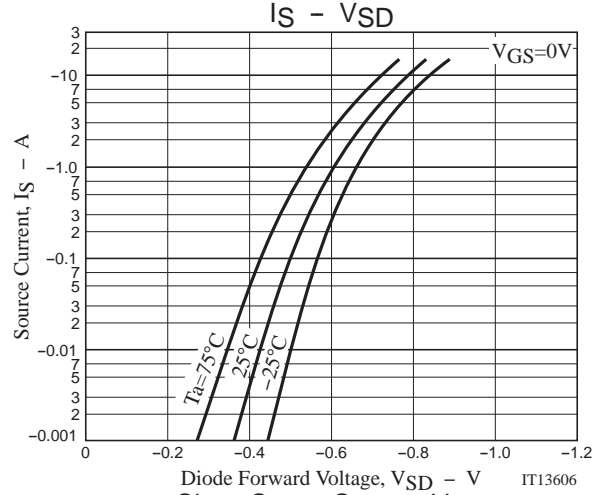
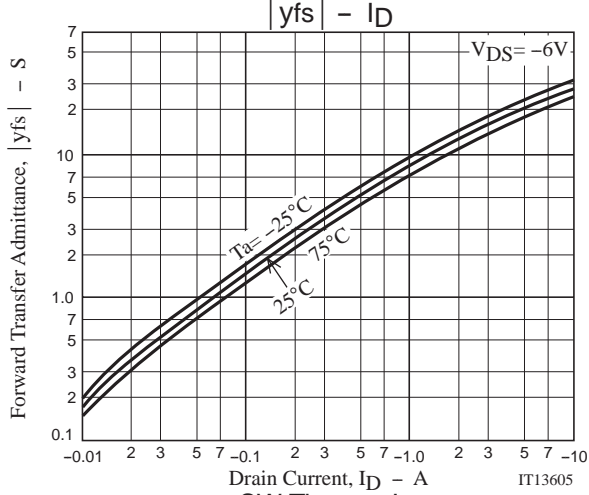
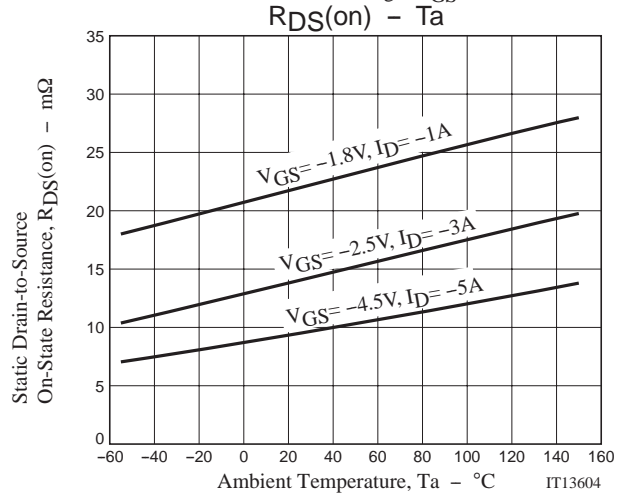
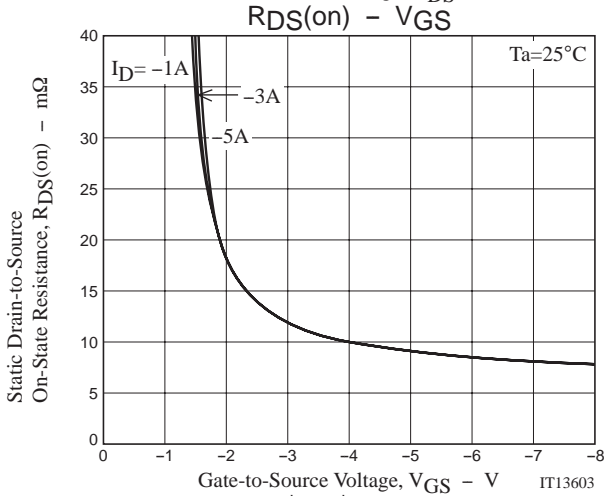
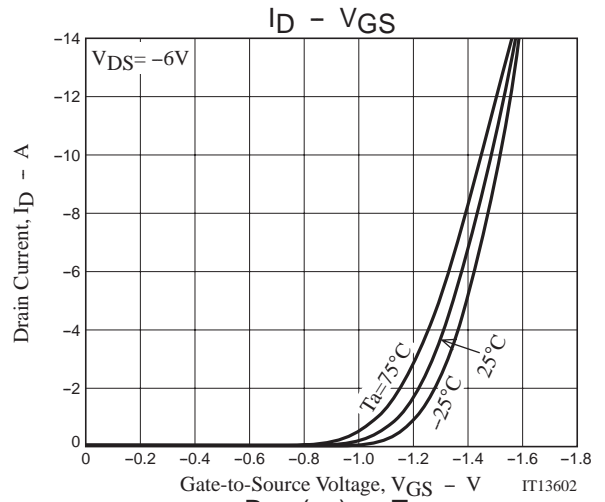
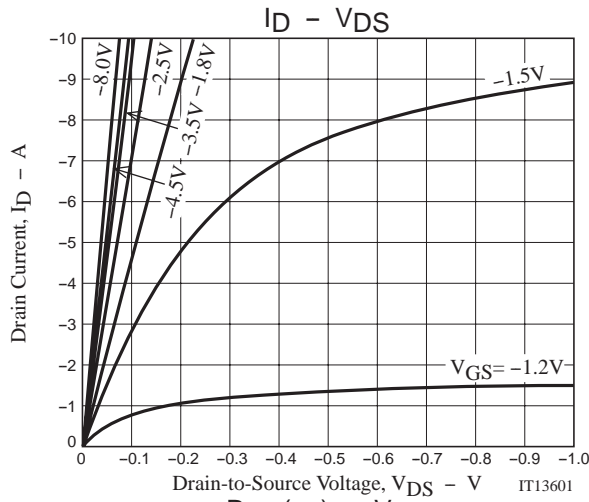


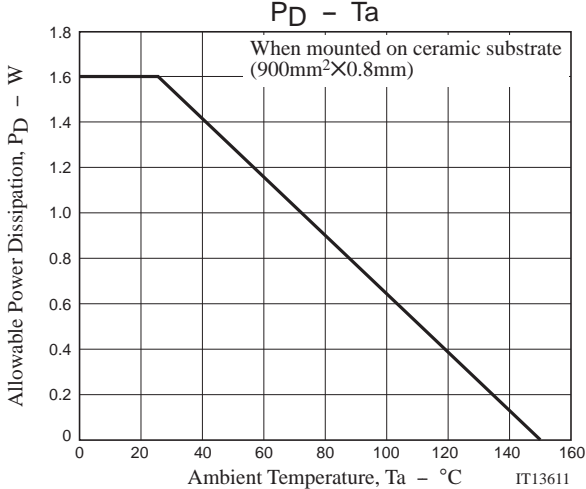
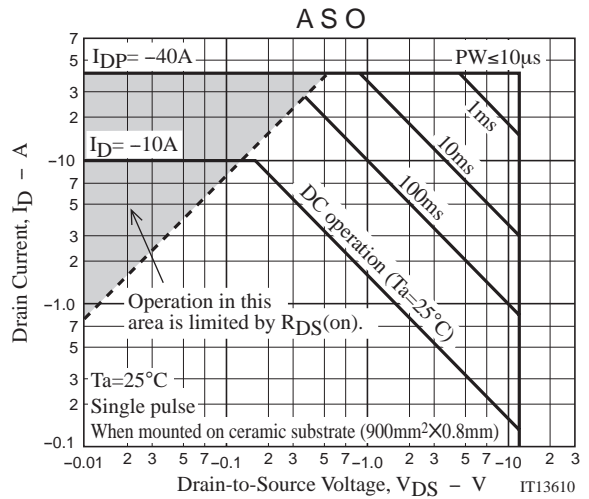
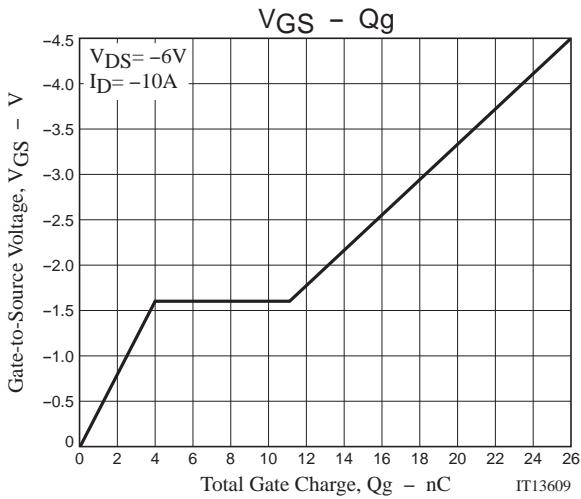
Electrical Connection



Switching Time Test Circuit







Note on usage : Since the ECH8308 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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